

Vishay Siliconix

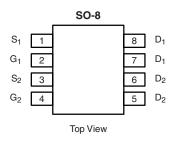
N- and P-Channel 30-V (D-S) MOSFET

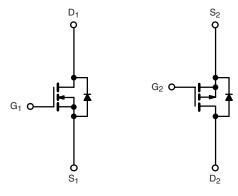
PRODUCT SUMMARY				
	V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	
N-Channel	30	0.025 at V _{GS} = 10 V	6.9	
		0.035 at V _{GS} = 4.5 V	5.8	
P-Channel	- 30	0.032 at V _{GS} = - 10 V	- 6.1	
		0.045 at V _{GS} = - 4.5 V	- 5.1	

FEATURES

- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC







N-Channel MOSFET

P-Channel MOSFET

Ordering Information: Si4542DY-T1-E3 (Lead (Pb)-free) Si4542DY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATIN	GS T _A = 25 °	°C, unless other	wise noted			
Parameter		Symbol	N-Channel	P-Channel	Unit	
Drain-Source Voltage		V _{DS}	30	- 30	V	
Gate-Source Voltage		V _{GS}	± 20	± 20		
	T _A = 25 °C	- I _D	6.9	- 6.1	٥	
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		5.5	- 4.9		
Pulsed Drain Current		I _{DM}	40	- 40	A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	1.7	- 1.7		
Marian Dissisting	T _A = 25 °C	P _D 2.0		.0	w	
Maximum Power Dissipation ^a	T _A = 70 °C	١D	1.3		vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	N- or P-Channel	Unit		
Maximum Junction-to-Ambient ^a	R _{thJA}	62.5	°C/W		

Notes:

a. Surface Mounted on FR4 board, $t \leq$ 10 s.

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Parameter	Symbol	Test Conditions		Min.	Тур.	Max.	Unit	
Static	-							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu A$	N-Ch	1.0				
		$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	P-Ch	- 1.0			V	
Onte Data Landara			N-Ch			± 100	~ ^	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	P-Ch			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$	N-Ch			1		
		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}$	P-Ch			- 1	μA	
		$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 55 ^{\circ}\text{C}$	N-Ch			25		
		V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 55 °C	P-Ch			- 25		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	N-Ch	20			А	
		$V_{DS} \le$ - 5 V, V_{GS} = - 10 V	P-Ch	- 20				
		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 6.9 \text{ A}$	N-Ch		0.020	0.025		
	_	V _{GS} = - 10 V, I _D = - 6.1 A	P-Ch		0.026	0.032		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 5.8 A	N-Ch		0.026	0.035	Ω	
		V _{GS} = - 4.5 V, I _D = - 5.1 A	P-Ch		0.036	0.045		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 6.9 A	N-Ch		25		_	
		V _{DS} = - 15 V, I _D = - 6.1 A	P-Ch		16		S	
Diode Forward Voltage ^a	V _{SD}	I _S = 1.7 A, V _{GS} = 0 V	N-Ch			1.2		
		I _S = - 1.7 A, V _{GS} = 0 V	P-Ch			- 1.2	V	
Dynamic ^b								
-	0	N-Channel	N-Ch		30	50	nC	
Total Gate Charge	Qg		P-Ch		32	50		
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 6.9 \text{ A}$	N-Ch		7.5			
	Ggs	P-Channel	P-Ch		7.0			
Gate-Drain Charge	Q _{gd}	V_{DS} = - 15 V, V_{GS} = - 10 V, I_D = - 6.1 A	N-Ch		3.5			
			P-Ch		5.0			
Gate Resistance	R _g		N-Ch	0.5	2	3.4	Ω	
			P-Ch N-Ch	2	4 12	6.8 20	──	
Turn-On Delay Time Rise Time	t _{d(on)} t _r	N-Channel	P-Ch		12	20		
		V_{DD} = 15 V, R_L = 10 Ω	N-Ch		10	20	ns	
		$\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 10 V, R_g = 6 Ω	P-Ch		10	20		
Turn-Off Delay Time	t _{d(off)}	P-Channel	N-Ch		60	90		
		$V_{DD} = -15 \text{ V}, \text{ R}_{L} = 10 \Omega$	P-Ch		55	80		
Fall Time	t _f	$I_D \cong$ - 1 Å, V_{GEN} = - 10 V, R_g = 6 Ω	N-Ch		15	30		
		-	P-Ch		25	40		
Source-Drain	t _{rr}	I _F = 1.7 A, dl/dt = 100 A/μs	N-Ch		50	90		
Reverse Recovery Time		I _F = - 1.7 A, dl/dt = 100 A/μs	P-Ch		50	90		
Reverse Recovery Time	Q _{rr}	I _F = 1.7 A, dl/dt = 100 A/μs	N-Ch		45		nC	
neverse necovery Time	Serr	I _F = - 1.7 A, dl/dt = 100 A/μs	I _F = - 1.7 A, dl/dt = 100 A/μs P-Ch 55				nC	

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

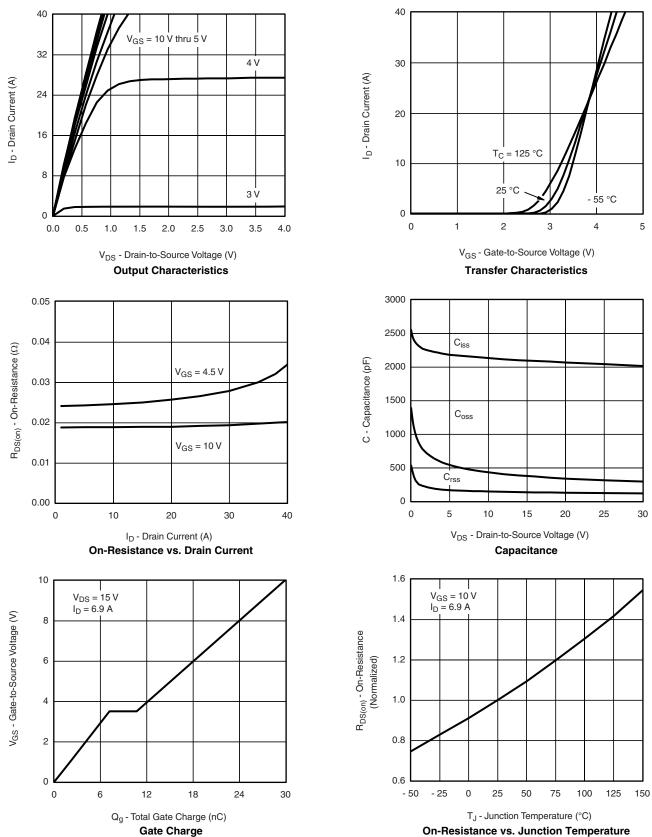
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



Si4542DY

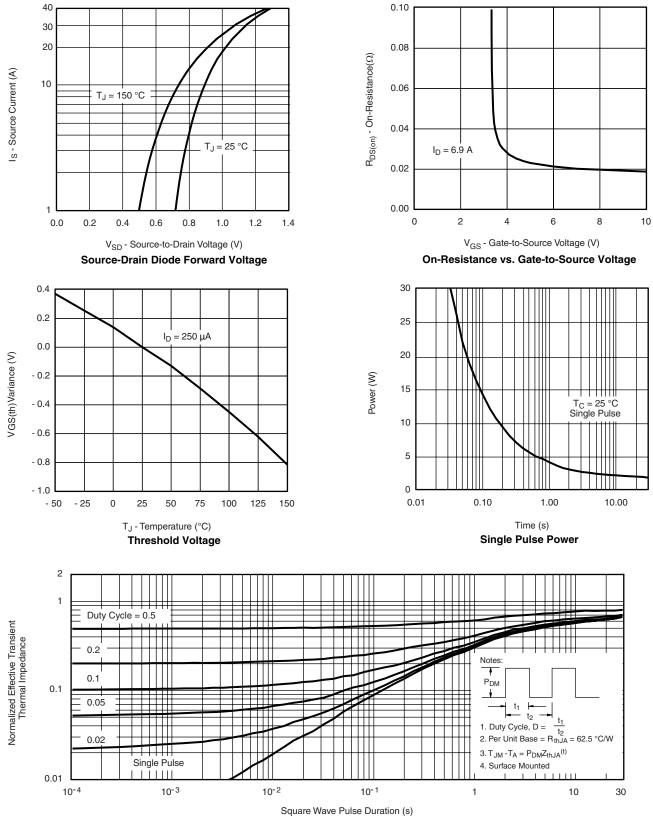
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N-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



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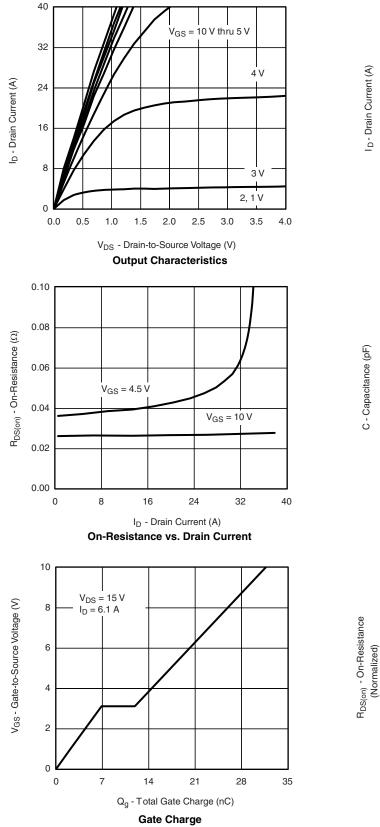


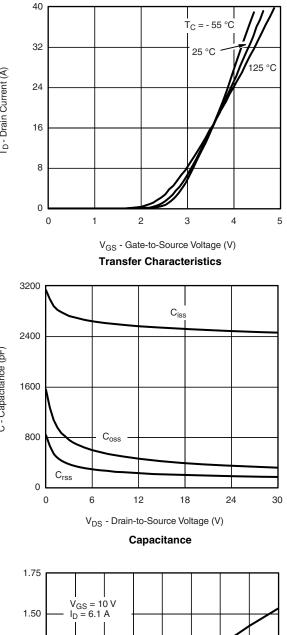


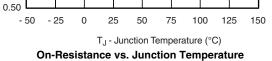
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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted







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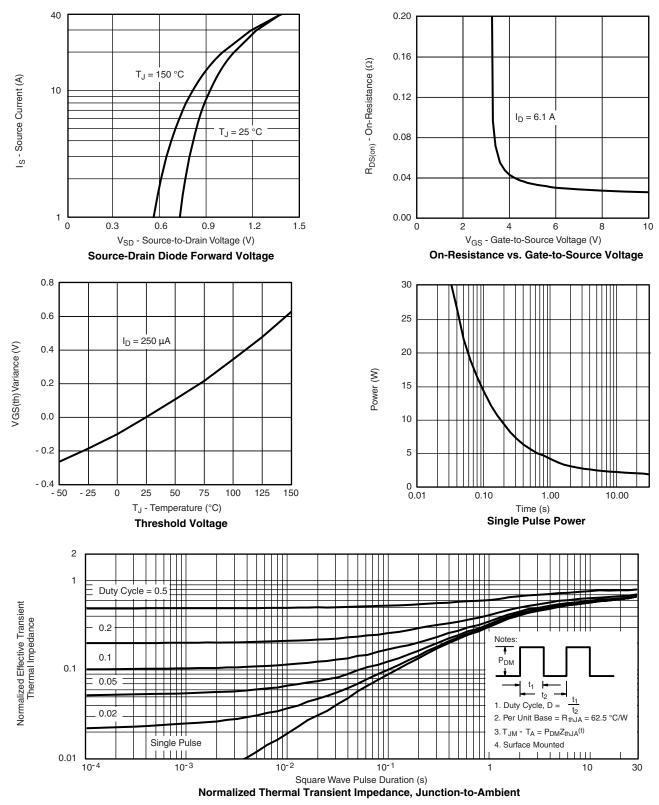
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P-CHANNEL TYPICAL CHARACTERISTICS 25 °C unless otherwise noted



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